Linear Single Cell Li-Ion Battery Charger IC

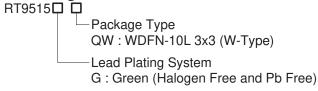
General Description

The RT9515 is a fully integrated low cost single-cell Lilon battery charger IC ideal for portable applications. The RT9515 is capable of being powered up from AC adapter. The RT9515 enters sleep mode when AC adapter is removed.

The RT9515 optimizes the charging task by using a control algorithm including preconditioning mode, fast charge mode and constant voltage mode. The charging task is terminated as the charge current drops below the preset threshold. The AC adapter charge current can be programmed up to 1A with an external resister. The internal thermal feedback circuitry regulates the die temperature to optimize the charge rate for all ambient temperatures.

The RT9515 features 18V maximum rating voltages for AC adapter. The other features are under voltage protection, over voltage protection for AC adapter supply and battery temperature monitoring.

Ordering Information



Note:

Richtek products are:

- RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- ▶ Suitable for use in SnPb or Pb-free soldering processes.

Features

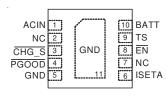
- 18V Maximum Rating for AC Adapter
- Internal Integrated P-MOSFETs
- AC Adapter Power Good Status Indicator
- Charge Status Indicator
- Under Voltage Protection
- Over Voltage Protection
- Automatic Recharge Feature
- Battery Temperature Monitoring
- Small 10-Lead WDFN Package
- Thermal Feedback Optimizing Charge Rate
- RoHS Compliant and Halogen Free

Applications

- Digital Cameras
- Cellular Phones
- Personal Data Assistants (PDAs)
- MP3 Players
- Handheld PCs

Pin Configurations

(TOP VIEW)



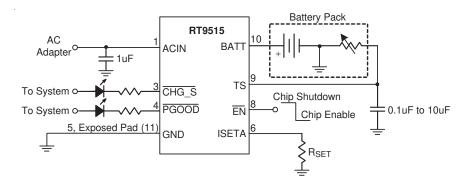
WDFN-10L 3x3

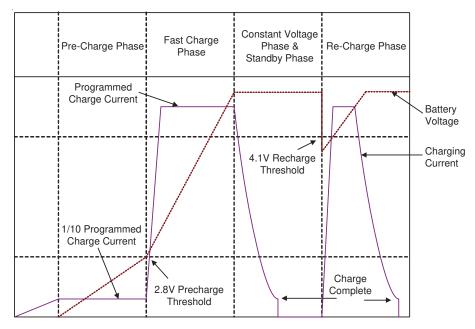
Marking Information

For marking information, contact our sales representative directly or through a Richtek distributor located in your area.



Typical Application Circuit





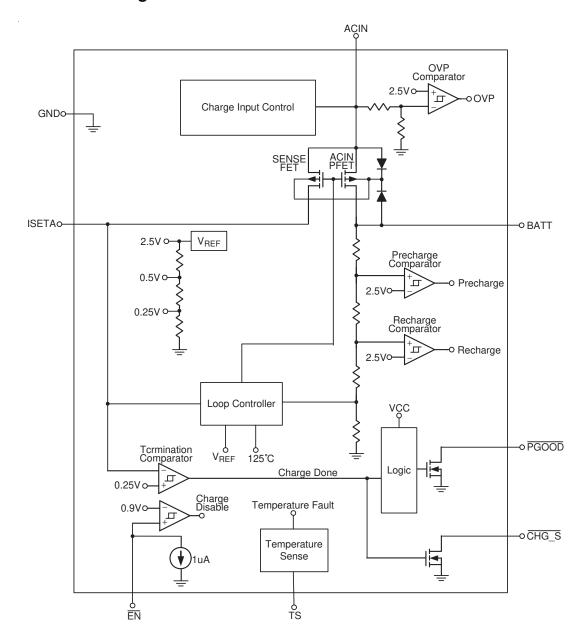
Functional Pin Description

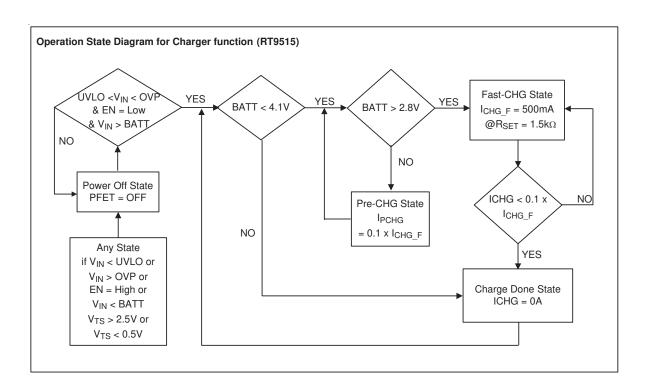
Pin No.	Pin Name	Pin Function		
1	ACIN	Wall Adaptor Charge Input Supply.		
2, 7	NC	No Internal Connection.		
3	CHG_S	Charge Status Indicator Output (open drain).		
4	PGOOD	Power Good Indicator Output (open drain).		
5	GND	Ground.		
6	ISETA	Wall Adaptor Supply Charge Current Set Point.		
8	EN	Charge Enable Input (active low).		
9	TS	Temperature Sense Input.		
10	BATT	Battery Charge Current Output.		
11 (Exposed Pad)	GND	Exposed pad should be soldered to PCB board and connected to GND.		

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Function Block Diagram







Absolute Maximum Ratings (Note 1)

• EN Input Voltage -0. • Output Current 1.2 • Power Dissipation, PD @ TA = 25°C 1.6 WDFN-10L 3x3 1.6 • Package Thermal Resistance (Note 2) 60° WDFN-10L 3x3, θJA 60° WDFN-10L 3x3, θJC 8.2 • Lead Temperature (Soldering, 10 sec.) 26° • Junction Temperature 15° • Storage Temperature Range -6° • ESD Susceptibility (Note 3) 18M (Human Body Mode) 2k° MM (Machine Mode) 20°	2A
 Power Dissipation, P_D @ T_A = 25°C WDFN-10L 3x3	
WDFN-10L 3x3 1.6 • Package Thermal Resistance (Note 2) 60° WDFN-10L 3x3, θ _{JA} 8.2 • Lead Temperature (Soldering, 10 sec.) 260° • Junction Temperature 150° • Storage Temperature Range 60° • ESD Susceptibility (Note 3) 26° • HBM (Human Body Mode) 2k°	67W
 Package Thermal Resistance (Note 2) WDFN-10L 3x3, θ_{JA}	667 W
WDFN-10L 3x3, θ _{JA}	
WDFN-10L 3x3, θ _{JC}	
 Lead Temperature (Soldering, 10 sec.)	°C/W
 Junction Temperature	2°C/W
Storage Temperature Range)°C
• ESD Susceptibility (Note 3) HBM (Human Body Mode) 2k')°C
HBM (Human Body Mode) 2k	5°C to 150°C
· · · · · · · · · · · · · · · · · · ·	
MM (Machine Mode) 200	
	V
Recommended Operating Conditions (Note 4)	
• ACIN Input Voltage Range 4.5	

• Junction Temperature Range ------ -40°C to 125°C
• Ambient Temperature Range ------ -40°C to 85°C

Electrical Characteristics

(ACIN = 5V, $T_A = 25$ °C, Unless Otherwise specification)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units		
Supply Input								
CIN UVLO Threshold Voltage V _{UVLO} Rising		Rising		3	3.5	V		
ACIN UVLO Hysteresis	V _{UVLO_Hys}		50	80	120	mV		
ACIN Standby Current	ISTBY	VBATT = 4.5V		300	500	uA		
ACIN Shutdown Current	I _{SHDN}	V _{EN} = High		50	100	uA		
ACIN Quiescent Current	IQ	V _{ACIN} = 4V, V _{USB} = 4V, V _{BATT} = 3V		150	250	uA		
BATT Sleep Leakage Current	I _{SLEEP}	VACIN = 4V, VUSB = 4V, VBATT = 4.5V		2	5	uA		
Voltage Regulation								
BATT Regulation Voltage	V _{REG}	I _{BATT} = 60mA	4.168	4.21	4.252	V		
Regulation Voltage Accuracy			-1		+1	%		
ACIN MOSFET	R _{DS(ON)_ACIN}	I _{BATT} = 500mA		600		mΩ		
Current Regulation								
ISETA Set Voltage (Fast Charge Phase)	V _{ISETA}	V _{BATT} = 3.5V	2.45	2.5	2.55	V		
Full Charge Setting Range	I _{CHG_F}		100		1200	mA		
ACIN Charge Current accuracy	I _{CHG_F}	$V_{BATT} = 3.8V$, $R_{ISET} = 1.5k\Omega$	-	500		mA		

To be continued



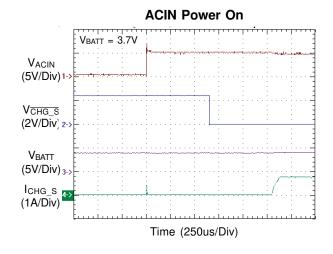
Parameter		Symbol	Test Conditions	Min	Тур	Max	Units
Precharge							
BATT Pre-Charge Rising Threshold		V _{PRECH}		2.6	2.8	3	V
BATT Pre-Charge Threshold Hysteresis		ΔVPRECH		50	100	200	mV
Pre-Charge Curre	ent	IPCHG	VBATT = 2V	8	10	12	%
Recharge Thres	hold						
BATT Re-Charge Falling Threshold Hysteresis		ΔV _{RECH_L}	V _{REG} – V _{BATT}	60	100	170	mV
Charge Termina	tion Detection						
ISETA Charge Termination Set Voltage		V _{TERM}	V _{BATT} = 4.2V	225	250	275	mV
Termination Current Ratio (default)		I _{TERM}	$V_{BATT} = 4.2V$		10		%
Logic Input/Out	Logic Input/Output						
CHG_S Pull Down Voltage		V CHG_S	TBD, ICHG_S = 5mA		65		m۷
PGOOD Pull Down Voltage		V _{PGOOD}	TBD, I PGOOD = 5mA		220		m۷
EN Threshold	Logic-High Voltage	V_{IH}		1.5			V
ENTITIESTICIO	Logic-Low Voltage	V _{IL}				0.4	V
EN Pin Input Cur	rent	IEN	$V_{\overline{EN}} = 2V$			2	uA
Battery Temperature Sense						•	
TS Pin Source Current		I _{TS}	V _{TS} = 1.5V	96	102	108	uA
TS Pin Threshold	Low Voltage	VTS_LOW	Falling	0.485	0.5	0.515	V
	High Voltage	V _{TS_HIGH}	Rising	2.45	2.5	2.55	V
Protection							
Thermal Regulation					125		°C
OVPSET			Internal Default		6.5		V

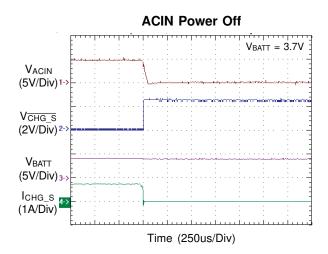
- **Note 1.** Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.
- Note 2. θ_{JA} is measured in the natural convection at $T_A = 25^{\circ}C$ on a high effective thermal conductivity test board (4 layers, 2S2P) of JEDEC 51-7 thermal measurement standard. The case point of θ_{JC} is on the expose pad for the package.
- Note 3. Devices are ESD sensitive. Handling precaution is recommended.
- Note 4. The device is not guaranteed to function outside its operating conditions.

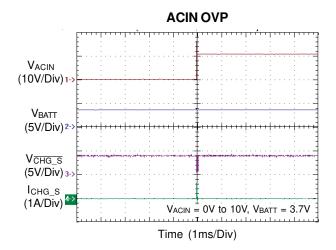
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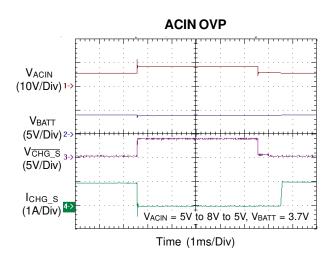


Typical Operating Characteristics









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Application Information

Automatically Power Source Selection

The RT9515 is a battery charger IC which is designed for Li-ion Battery with 4.21V rated voltage.

ACIN Mode: When the ACIN input voltage is higher than the UVP voltage level (3V) and lower than OVP voltage level (6.5V), the RT9515 will turn on ACIN P-MOSFET.

Sleep Mode: The RT9515 will enter Sleep Mode when ACIN input voltage are removed. This feature provides low leakage current from the battery during the absence of input supply.

ACIN Over Voltage Protection

The ACIN input voltage is monitored by an internal OVP comparator. The comparator has an accurate reference of 2.5V from the band-gap reference. The OVP threshold is set by the internal resistive. The protection threshold is set to 6.5V. When the input voltage exceeds the threshold, the comparator outputs a logic signal to turn off the power P-MOSFET to prevent the high input voltage from damaging the electronics in the handheld system. When the input over oltage condition is removed (ACIN < 6V), the comparator re-enables the output by running through the soft-start.

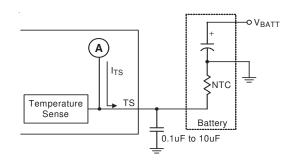
Battery Temperature Monitoring

The RT9515 continuously monitors battery temperature by measuring the voltage between the TS and GND pins. The RT9515 has an internal current source to provide the bias for the most common $10k\Omega$ negative-temperature coefficient thermal resistor (NTC) (see Figure 1). The RT9515 compares the voltage on the TS pin against the internal VTS HIGH and VTS LOW thresholds to determine if charging is allowed.

When the temperature outside the VTS HIGH and VTS LOW thresholds is detected, the device will immediately stop the charge. The RT9515 stops charge and keep monitoring the battery temperature when the temperature sense input voltage is back to the threshold between VTS HIGH and VTS LOW, the charger will be resumed. Charge is resumed when the temperature returns to the normal range. However, the user may modify thresholds by the negative-temperature coefficient thermal

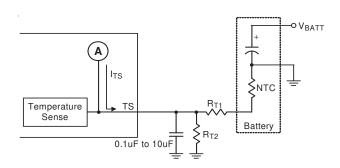
resistor or adding two external resistors. (see Figure 2.)

The capacitor should be placed close to TS(Pin 9) and connected to the ground plane. The capacitance value (0.1uF to 10uF) should be selected according to the quality of PCB layout. It is recommended to use 10uF if the layout is poor to prevent noise.



 $V_{TS} = I_{TS} \times R_{NTC}$ Turn off when $V_{TS} \ge 2.5 V$ or $V_{TS} \le 0.5 V$

Figure 1. Temperature Sensing Configuration



$$\begin{split} V_{TS} &= I_{TS} \, \frac{R_{T2} \times (R_{T1} \, + R_{NTC})}{R_{T1} \, + R_{T2} \, + R_{NTC}} \\ Turn \ \text{off when} \ V_{TS} &\geq 2.5 V \ \text{or} \ V_{TS} \leq 0.5 V \end{split}$$

Figure 2. Temperature Sensing Circuit

Fast-Charge Current Setting

The RT9515 offers ISETA pin to determine the ACIN charge current from 100mA to 1.2A. The charge current can be calculated as following equation.

$$I_{CHG_F} = K \frac{V_{ISETA}}{R_{SET}}$$



The parameter K = 300 ; V_{ISETA} = 2.5V. R_{SET} is the resistor connected between the ISETA and GND.

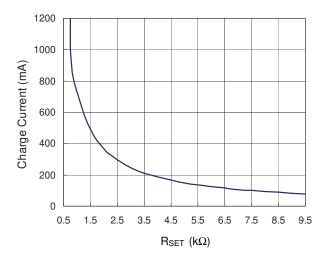


Figure 3. Charge Current Setting

Pre- Charge Current Setting

During a charge cycle if the battery voltage is below the VPRECH threshold, the RT9515 applies a pre-charge mode to the battery. This feature revives deeply discharged cells and protects battery life. The RT9515 internally determines the pre-charge rate as 10% of the fast-charge current.

Battery Voltage Regulation

The RT9515 monitors the battery voltage through the BATT pin. Once the battery voltage level closes to the VREG threshold, the RT9515 voltage enters constant phase and the charging current begins to taper down. When battery voltage is over the VREG threshold, the RT9515 will stop charge and keep to monitor the battery voltage. However, when the battery voltage decreases 100mV below the V_{REG} , it will be recharged to keep the battery voltage.

Charge Status Outputs

The open-drain CHG_S and PGOOD outputs indicate various charger operations as shown in the following table.

These status pins can be used to drive LEDs or communicate to the host processor. Note that ON indicates the open-drain transistor is turned on and LED is bright.

Charge State		CHG_S	PGOOD	
ACIN	Charge	ON	ON	
	Charge done	OFF	ON	

Temperature Regulation and Thermal Protection

In order to maximize the charge rate, the RT9515 features a junction temperature regulation loop. If the power dissipation of the IC results in a junction temperature greater than the thermal regulation threshold (125°C), the RT9515 throttles back on the charge current in order to maintain a junction temperature around the thermal regulation threshold (125°C). The RT9515 monitors the junction temperature, T_J , of the die and disconnects the battery from the input if T_J exceeds 125°C. This operation continues until junction temperature falls below thermal regulation threshold (125°C) by the hysteresis level. This feature prevents the chip from damaging.

Selecting the Input and Output Capacitors

In most applications, the most important is the high-frequency decoupling capacitor on the input of the RT9515. A 1uF ceramic capacitor, placed in close proximity to input pin and GND pin is recommended. In some applications depending on the power supply characteristics and cable length, it may be necessary to add an additional 10uF ceramic capacitor to the input. The RT9515 requires a small output capacitor for loop stability. A 1uF ceramic capacitor placed between the BATT pin and GND is typically sufficient.

Thermal Considerations

For continuous operation, do not exceed absolute maximum operation junction temperature. The maximum power dissipation depends on the thermal resistance of IC package, PCB layout, the rate of surroundings airflow and temperature difference between junction to ambient. The maximum power dissipation can be calculated by following formula:

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

Where $T_{J(MAX)}$ is the maximum operation junction temperature 125°C, T_A is the ambient temperature and the θ_{JA} is the junction to ambient thermal resistance.

For recommended operating conditions specification, where $T_{J(MAX)}$ is the maximum junction temperature of the die (125°C) and T_A is the ambient temperature. The junction to ambient thermal resistance θ_{JA} is layout dependent. For WDFN-10L 3x3 packages, the thermal resistance θ_{JA} is 60°C/W on the standard JEDEC 51-7 four layers thermal test board. The maximum power dissipation at T_A = 25°C can be calculated by following formula :

 $P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C) / (60^{\circ}C/W) = 1.667W$ for WDFN-10L 3x3 packages

The maximum power dissipation depends on operating ambient temperature for fixed $T_{J(MAX)}$ and thermal resistance θ_{JA} . For WDFN-10L 3x3 package, the Figure 4 of derating curves allows the designer to see the effect of rising ambient temperature on the maximum power allowed.

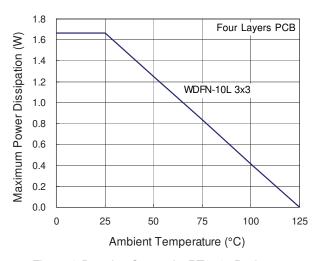


Figure 4. Derating Curves for RT9515 Package

Layout Considerations

For the best performance of the RT9515, the following PCB layout guidelines must be strictly followed.

- Place the input and output capacitors as close as possible to the input and output pins respectively for good filtering.
- ▶ Keep the main power traces as wide and short as possible.
- The connection of R_{SETA} should be isolated from other noisy traces. The short wire is recommended to prevent EMI and noise coupling.

- Connect the GND and Exposed Pad to a strong ground plane for maximum thermal dissipation and noise protection.
- ▶ The TS's capacitor should be placed close to TS (Pin 9) and connected to ground plane. If the PCB layout is poor, it is recommended to use a 10uF at C2 to prevent noise.

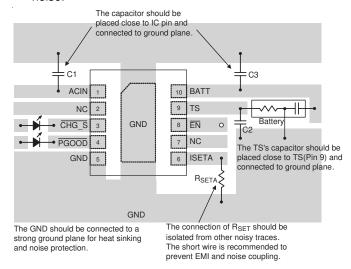
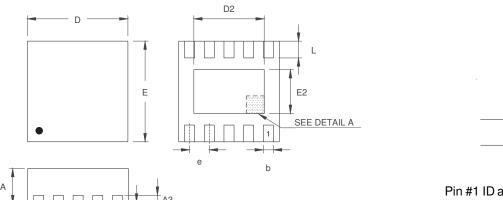


Figure 5. PCB Layout Guide

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Outline Dimension



DETAIL APin #1 ID and Tie Bar Mark Options

:: The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min	Max	Min	Max	
А	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A3	0.175	0.250	0.007	0.010	
b	0.180	0.300	0.007	0.012	
D	2.950	3.050	0.116	0.120	
D2	2.300	2.650	0.091	0.104	
Е	2.950	3.050	0.116	0.120	
E2	1.500	1.750	0.059	0.069	
е	0.5	500	0.0)20	
L	0.350	0.450	0.014	0.018	

W-Type 10L DFN 3x3 Package

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